54F533,74F533

54F533 74F533 Octal Transparent Latch with TRI-STATE(RM) Outputs



Literature Number: SNOS200A



54F/74F533 Octal Transparent Latch with TRI-STATE® Outputs

General Description

The 'F533 consists of eight latches with TRI-STATE outputs for bus organized system applications. The flip-flops appear transparent to the data when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup times is latched. Data appears on the bus when the Output Enable ($\overline{\text{OE}}$) is LOW. When $\overline{\text{OE}}$ is HIGH the bus output is in the high impedance state. The 'F533 is the same as the 'F373, except that the outputs are inverted.

Features

- Eight latches in a single package
- TRI-STATE outputs for bus interfacing
- Inverted version of the 'F373
- Guaranteed 4000V minimum ESD protection

| Commercial | Military | Package Number | Package Description |
|-------------------|-------------------|-------------------|---|
| 74F533PC | | N20A | 20-Lead (0.300" Wide) Molded Dual-In-Line |
| | 54F533DM (Note 2) | J20A | 20-Lead Ceramic Dual-In-Line |
| 74F533SC (Note 1) | | M20B | 20-Lead (0.300" Wide) Molded Small Outline, JEDEC |
| 74F533SJ (Note 1) | | M20D | 20-Lead (0.300" Wide) Molded Small Outline, EIAJ |
| | 54F533FM (Note 2) | W20A | 20-Lead Cerpack |
| | 54F533LM (Note 2) | E20A | 20-Lead Ceramic Leadless Chip Carrier, Type C |

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbols Connection Diagrams Pin Assignment for DIP, SOIC and Flatpak Pin Assignment IEEE/IEC for LCC ŌĒ ·v_{cc} 20 ō₀-19 **−**ō₇ -D₇ 1 D Do-18 3 D₀ 2 0 0 0 1 0E 20 V_{CC} 19 0₇ 0, D_1 D₁ -D₆ -ō₆ D_2 02 ō, -ō₅ D_3 $\bar{0}_3$ \bar{o}_2 D₄ 13 $\bar{0}_4$ D_2 -D₅ D_5 Ō₅ D_3 -D4 14 15 16 17 18 De 06 Ō3 -ō₄ D₅ O 5 O 6 D 6 D 7 07 GND --LE TL/F/9548-3 TL/F/9548-4 TL/F/9548-2 D₂ D₃ D₄ D₅ D₆ D₇ 01 02 03 04 05 06 07 TL/F/9548-1 TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Unit Loading/Fan Out

| | | 54F/74F | | | |
|-----------------------------------|----------------------------------|------------------|---|--|--|
| Pin Names | Description | U.L. HIGH/LOW | Input I _{IH} /I _{IL} Output I _{OH} /I _{OL} | | |
| D ₀ -D ₇ | Data Inputs | 1.0/1.0 | 20 μA/ -0.6 mA | | |
| LE | Latch Enable Input (Active HIGH) | 1.0/1.0 | 20 μA/ - 0.6 mA | | |
| ŌĒ | Output Enable Input (Active LOW) | 1.0/1.0 | 20 μA/ - 0.6 mA | | |
| $\overline{O}_0 - \overline{O}_7$ | Complementary TRI-STATE Outputs | 150/40 (33.3) | −3 mA/24 mA (20 mA) | | |

Function Table

| | Inputs | | Output |
|----|--------|---|------------------|
| LE | ŌĒ | D | ō |
| Н | L | Н | L |
| Н | L | L | Н |
| L | L | X | \overline{O}_0 |
| X | Н | Χ | Z |

H = HIGH Voltage Level L = LOW Voltage Level

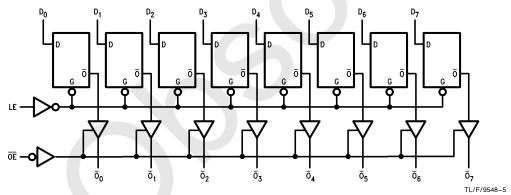
X = Immaterial

Functional Description

The 'F533 contains eight D-type latches with TRI-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the Dn inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D in-

puts a setup time preceding the HIGH-to-LOW transition of LE. The TRI-STATE buffers are controlled by the Output Enable (OE) input. When OE is LOW, the buffers are in the bi-state mode. When $\overline{\text{OE}}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \mbox{Storage Temperature} & -65^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \mbox{Ambient Temperature under Bias} & -55^{\circ}\mbox{C to} + 125^{\circ}\mbox{C} \\ \mbox{Junction Temperature under Bias} & -55^{\circ}\mbox{C to} + 175^{\circ}\mbox{C} \\ \mbox{Plastic} & -55^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \end{array}$

V_{CC} Pin Potential to

Ground Pin -0.5V to +7.0V Input Voltage (Note 2) -0.5V to +7.0V Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Output in HIGH State (with $V_{CC} = 0V$)

 $\begin{array}{lll} \text{Standard Output} & -0.5 \text{V to V}_{\text{CC}} \\ \text{TRI-STATE Output} & -0.5 \text{V to } +5.5 \text{V} \end{array}$

Current Applied to Output in LOW State (Max) twice the rated I_{OL} (mA) ESD Last Passing Voltage (Min) 4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Supply Voltage

Military + 4.5V to + 5.5V Commercial + 4.5V to + 5.5V

DC Electrical Characteristics

| Symbol | nbol Parameter | | 54F/74F | | | Units | V | Conditions |
|-------------------|---------------------------------------|--|--|----|-------------|-----------------|------------|---|
| Symbol | Parame | ter | Min Typ Max | | Units | V _{CC} | Conditions | |
| V _{IH} | Input HIGH Voltage | | 2.0 | | | V | | Recognized as a HIGH Signal |
| V_{IL} | Input LOW Voltage | | | | 0.8 | V | | Recognized as a LOW Signal |
| V_{CD} | Input Clamp Diode Vo | oltage | | | -1.2 | V | Min | $I_{\text{IN}} = -18 \text{ mA}$ |
| V _{OH} | Output HIGH Voltage | 54F 10% V _{CC} 54F 10% V _{CC} 74F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC} 74F 5% V _{CC} | 2.5 2.4 2.5 2.4 2.7 2.7 | | | V | Min | $\begin{split} I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ \end{split}$ |
| V _{OL} | Output LOW Voltage | 54F 10% V _{CC} 74F 10% V _{CC} | | | 0.5 0.5 | ٧ | Min | I _{OL} = 20 mA I _{OL} = 24 mA |
| I _{IH} | Input HIGH Current | 54F 74F | | | 20.0 5.0 | μΑ | Max | V _{IN} = 2.7V |
| I _{BVI} | Input HIGH Current Breakdown Test | 54F 74F | | | 100 7.0 | μΑ | Max | V _{IN} = 7.0V |
| I _{BVIT} | Input HIGH Current Breakdown (I/O) | 54F 74F | | | 1.0 0.5 | mA | Max | V _{IN} = 5.5V |
| I _{CEX} | Output HIGH Leakage Current | 54F 74F | | | 250 50 | μΑ | Max | $V_{OUT} = V_{CC}$ |
| V_{ID} | Input Leakage Test | 74F | 4.75 | | | V | 0.0 | $I_{\text{ID}} = 1.9 \mu\text{A}$ All Other Pins Grounded |
| I _{OD} | Output Leakage Circuit Current | 74F | | | 3.75 | μΑ | 0.0 | V _{IOD} = 150 mV All Other Pins Grounded |
| I _{IL} | Input LOW Current | | | | -0.6 | mA | Max | V _{IN} = 0.5V |
| lozh | Output Leakage Current | | | | 50 | μΑ | Max | V _{OUT} = 2.7V |
| l _{OZL} | Output Leakage Current | | | | -50 | μΑ | Max | V _{OUT} = 0.5V |
| los | Output Short-Circuit Current | | -60 | | -150 | mA | Max | $V_{OUT} = 0V$ |
| I_{ZZ} | Bus Drainage Test | | | | 500 | μΑ | 0.0V | V _{OUT} = 5.25V |
| I _{CCZ} | Power Supply Current | | | 41 | 61 | mA | Max | V _O = HIGH Z |

AC Electrical Characteristics

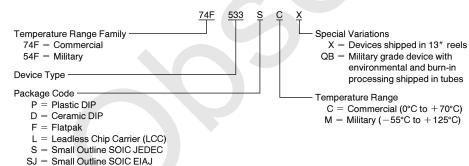
| Symbol | Parameter | V | 74F T _A = +25°0 / _{CC} = +5.0 C _L = 50 pF | V | T _A , V _C | 4F C = Mil 50 pF | T _A , V _{CC} | 4F = Com 50 pF | Units |
|------------------|---|------------|---|-------------|---------------------------------|------------------------|----------------------------------|----------------------|-------|
| | | Min | Тур | Max | Min | Max | Min | Max | |
| t _{PLH} | Propagation Delay D_n to \overline{O}_n | 4.0 2.5 | 6.7 4.4 | 9.0 7.0 | 4.0 2.5 | 12.0 9.0 | 4.0 2.5 | 10.0 8.0 | ns |
| t _{PLH} | Propagation Delay LE to \overline{O}_{n} | 5.0 3.0 | 7.1 4.7 | 11.0 7.0 | 5.0 3.0 | 14.0 9.0 | 5.0 3.0 | 13.0 8.0 | ns |
| t _{PZH} | Output Enable Time | 2.0 2.0 | 5.9 5.6 | 10.0 7.5 | 2.0 2.0 | 12.5 10.5 | 2.0 2.0 | 11.0 8.5 | ns |
| t _{PHZ} | Output Disable Time | 1.5 1.5 | 3.4 2.7 | 6.5 5.5 | 1.5 1.5 | 8.5 7.5 | 1.5 1.5 | 7.0 6.5 | ns |

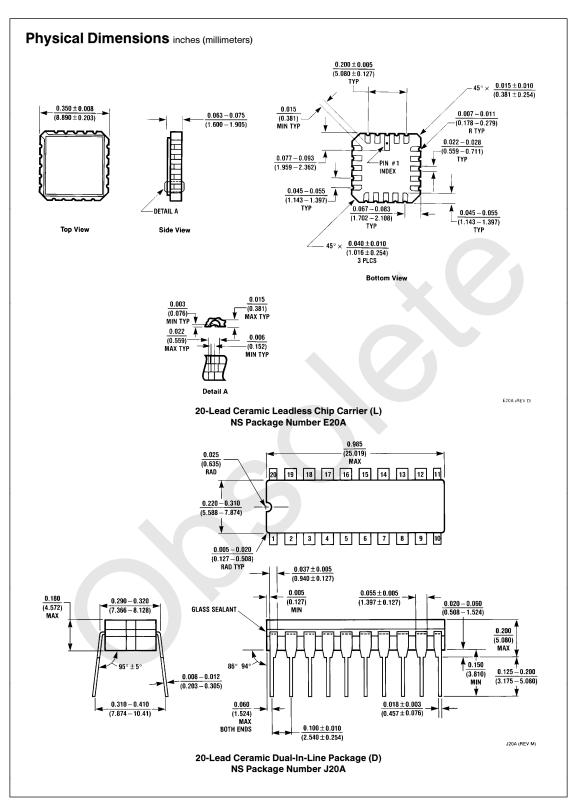
AC Operating Requirements

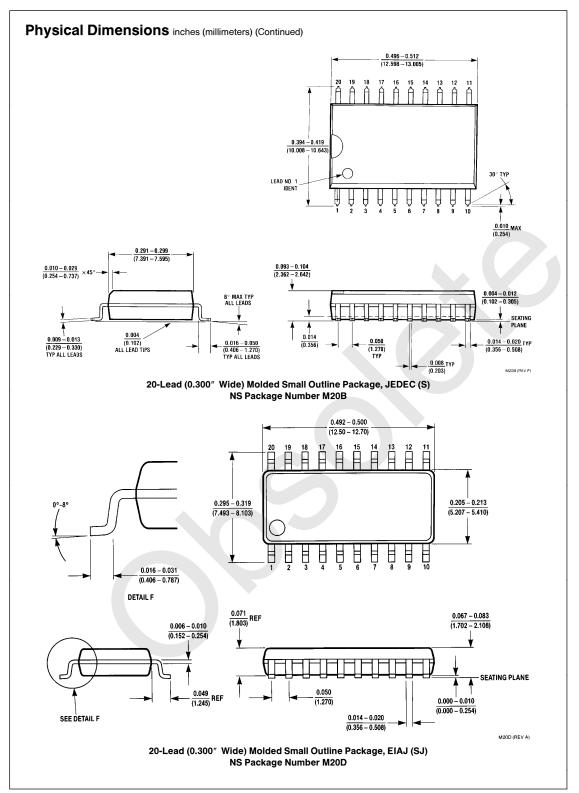
| | | $74F$ $T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ | | 54 | F | 74F | | |
|--|---|---|-----|------------------------------|-----|---------------------|-----|-------|
| Symbol | Parameter | | | ${\sf T_A,V_{CC}}={\sf Mil}$ | | $T_A, V_{CC} = Com$ | | Units |
| | | Min | Max | Min | Max | Min | Max | > |
| t _s (H) t _s (L) | Setup Time, HIGH or LOW D _n to LE | 2.0 2.0 | | 2.0 2.0 | | 2.0 2.0 | | ns |
| t _h (H) t _h (L) | Hold Time, HIGH or LOW D _n to LE | 3.0 3.0 | | 3.0 3.0 | | 3.0 3.0 | | ns |
| t _w (H) | LE Pulse Width, HIGH | 6.0 | | 6.0 | | 6.0 | | ns |

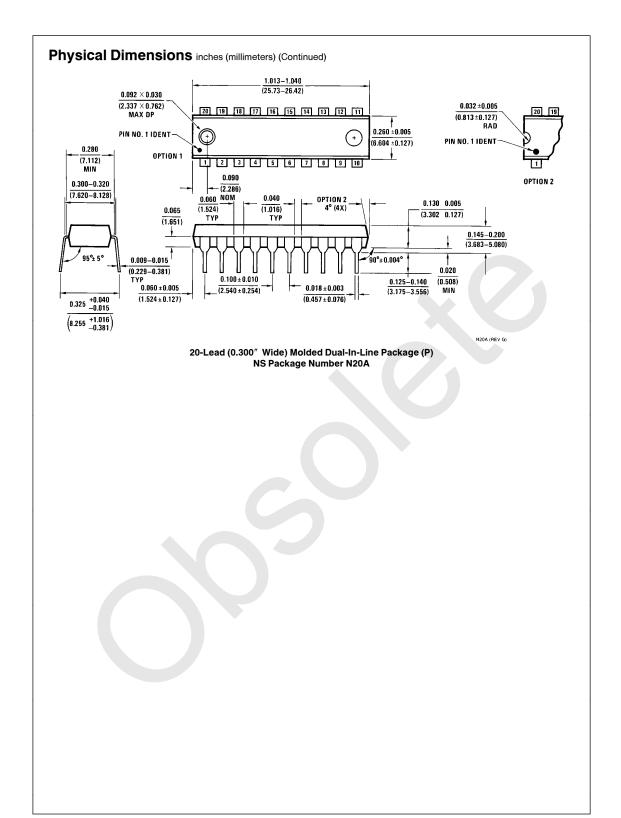
Ordering Information

The device number is used to form part of a simplified purchasing code where a package type and temperature range are defined as follows:

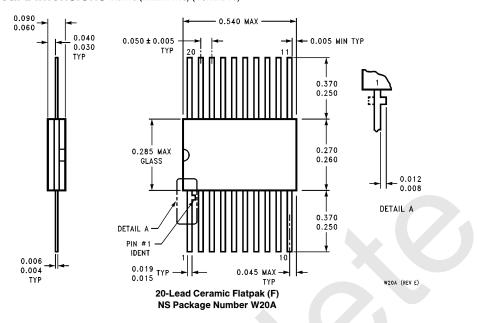








Physical Dimensions inches (millimeters) (Continued)



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